

## LESDA6V1W6T1G *Transil array for data protection*

### General Description

The LESDA6V1W6T1G is a monolithic suppressor designed to protect components connected to data and transmission lines against ESD. The device clamp the voltage just above the logic level supply for positive transients, and to a diode drop below ground for negative transients.

### Applications

- Computers
- Printers
- Communication systems
- Cellular phones handsets and accessories
- Wireline and wireless telephone sets
- Set top boxes

### Features

- 4 Unidirectional Transil functions
- Breakdown voltage:
- $V_{BR} = 6.1 \text{ V min. and } 25 \text{ V min.}$
- Low leakage current:  $< 1 \text{ mA}$
- Very small PCB area  $< 4.2 \text{ mm}^2$  typically
- High ESD protection level: up to 25 kV
- High integration

### Complies with the following standards

#### IEC61000-4-2

Level 4 15 kV (air discharge)  
9 kV(contact discharge)

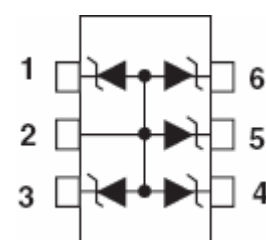
#### MIL STD 883E - Method 3015-7 Class 3

25 kV HBM (Human Body Model)



**SOT-363**

### Functional diagram



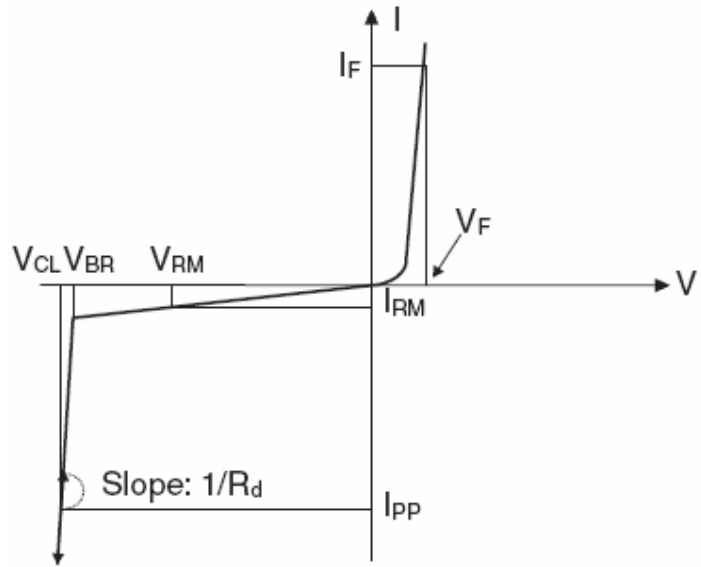
**LESD6V1W6T1G**

### Absolute Ratings ( $T_{amb}=25^{\circ}\text{C}$ )

| Symbol    | Parameter   | Value       | Units              |
|-----------|---|-------------|--------------------|
| $P_{PP}$  | Peak Pulse Power<br>( $t_p = 8/20\mu\text{s}$ )   | 100         | W                  |
| $T_L$     | Maximum lead temperature for soldering during 10s | 260         | $^{\circ}\text{C}$ |
| $T_{stg}$ | Storage Temperature Range                         | -40 to +125 | $^{\circ}\text{C}$ |
| $T_{op}$  | Operating Temperature Range                       | -40 to +125 | $^{\circ}\text{C}$ |

### Electrical Parameter

| Symbol     | Parameter                       |
|------------|---------------------------------|
| $V_{RM}$   | Stand-off voltage               |
| $V_{BR}$   | Breakdown voltage               |
| $V_{CL}$   | Clamping voltage                |
| $I_{RM}$   | Leakage current                 |
| $I_{PP}$   | Peak pulse current              |
| $I_R$      | Reverse current                 |
| $I_F$      | Forward current                 |
| $\alpha T$ | Voltage temperature coefficient |
| $V_F$      | Forward voltage drop            |
| C          | Capacitance                     |
| $R_d$      | Dynamic                         |



### Electrical Characteristics

| Part Numbers  | $V_{BR}$ |      | $I_R$ | $V_{RM}$ | $I_{RM}$ | $V_F$ | $I_F$ | $R_d$               | $\alpha T$          | C            |
|---------------|----------|------|-------|----------|----------|-------|-------|---------------------|---------------------|--------------|
|               | Min.     | Max. |       |          |          | Max.  |       | Typ. <sup>(1)</sup> | Max. <sup>(2)</sup> | Typ. 0v bias |
|               | v        | v    |       |          |          | v     |       | $\Omega$            | $10^{-4}/^{\circ}C$ | pF           |
| LESDA6V1W6T1G | 6.1      | 7.2  | 1     | 3        | 1        | 1.25  | 200   | 0.61                | 6                   | 50           |

1. Square pulse  $I_{PP}=15A, t_p=2.5\mu s$  2.  $V_{BR}=\alpha T * (T_{amb}-25^{\circ}C) * V_{BR}(25^{\circ}C)$

### Typical Characteristics

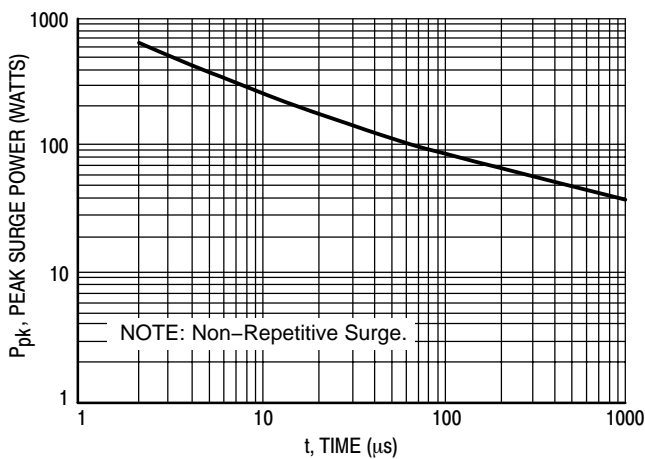


Figure 1. Pulse Width

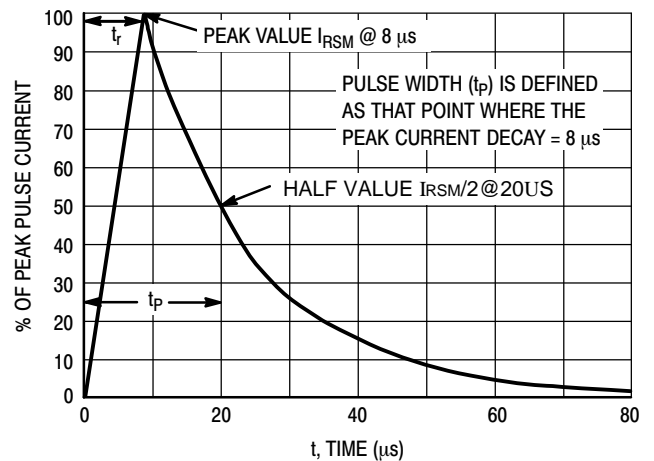


Figure 2. 8 x 20 µs Pulse Waveform

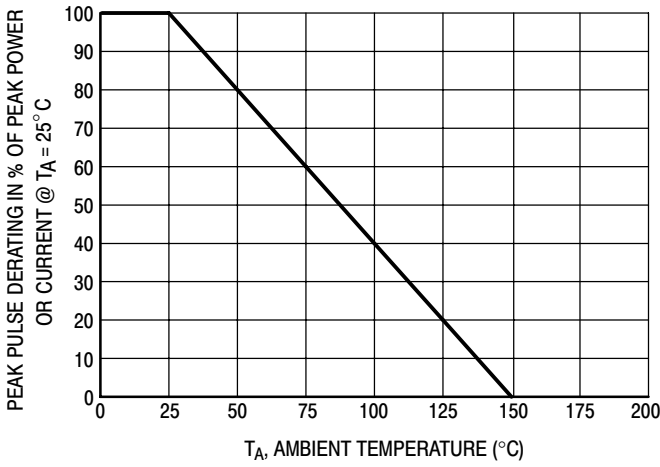


Figure 3. Pulse Derating Curve

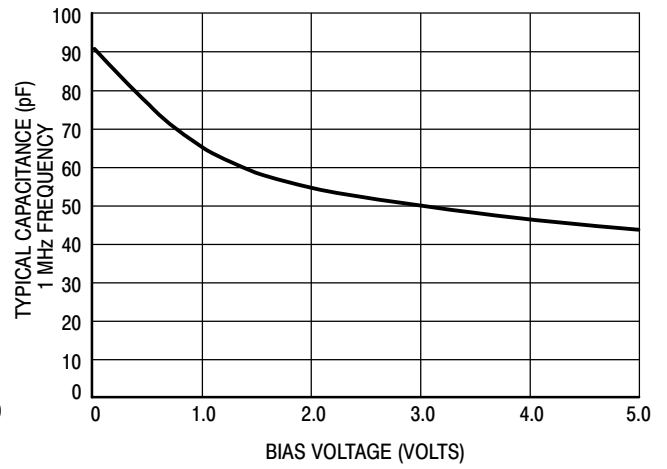


Figure 4. Capacitance

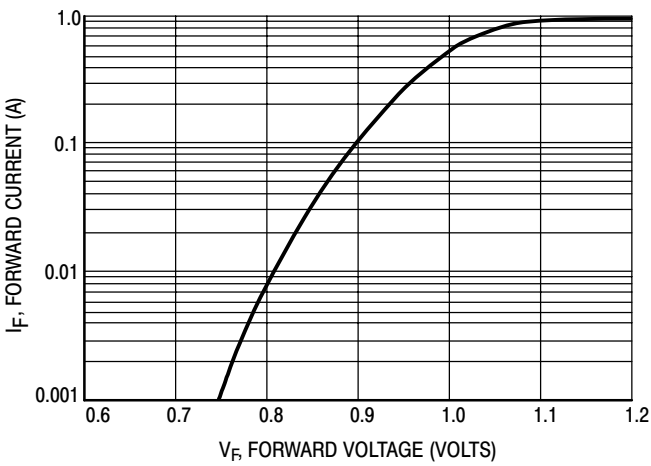


Figure 5. Forward Voltage

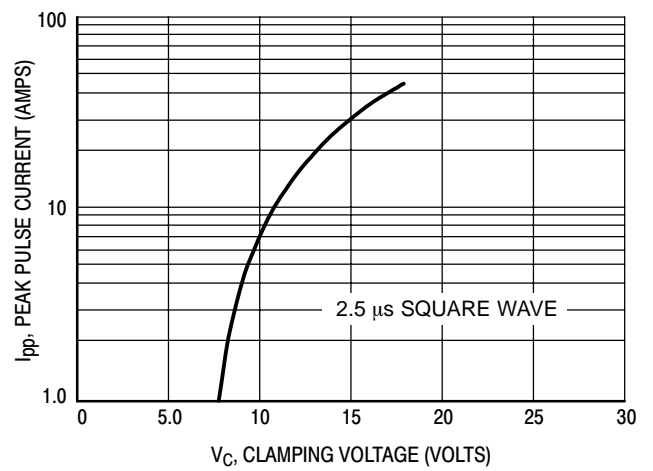
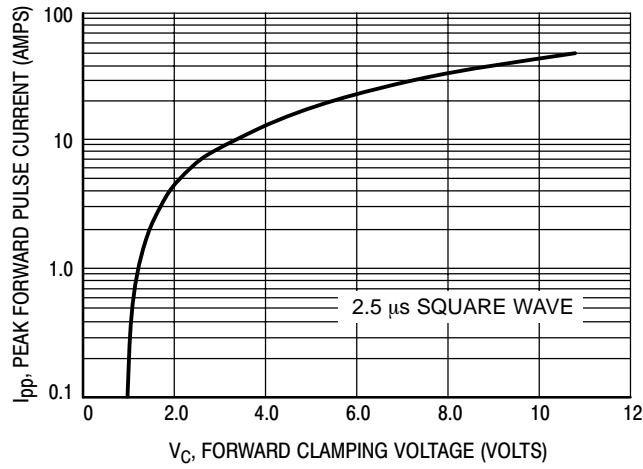


Figure 6. Clamping Voltage versus Peak Pulse Current (Reverse Direction)



**Figure 7. Clamping Voltage versus Peak Pulse Current (Forward Direction)**

**Package mechanical data**

**SOT-363 Package**

